

REMARKS/ARGUMENTS

The applicant's attorneys appreciate the Examiner's comments.

Responsive to the objections set forth in paragraphs 3 and 5 of the Office Action, the specification has been corrected. Withdrawal of the objections is requested.

Responsive to the objection set forth in paragraph 4 of the Office Action, Fig. 1 has been corrected. Withdrawal of the objection is requested.

Responsive to the objection set forth in paragraph 6 of the Office Action, claim 1 has been corrected. Withdrawal of the objection is requested.

Responsive to the rejection of claims 1-10 under 35 U.S.C. §112, second paragraph, claim 1 has been corrected. Reconsideration is requested.

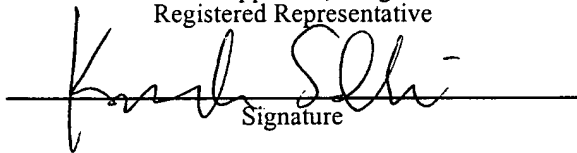
Responsive to the question "What is 'Sipos' in claims 3, 4, lines 3?", sipos is an acronym for semi-insulating polycrystalline silicon, which is obtained by adding oxygen or nitrogen to silicon during growth as is well known in the art.

The application is believed to be in condition for allowance. Such action is earnestly solicited.

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as First Class Mail in an envelope addressed to: Mail Stop Amendment, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on November 11, 2004:

Kourosh Salehi

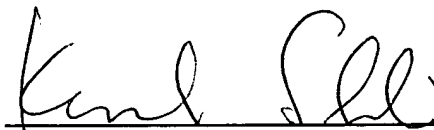
Name of applicant, assignee or
Registered Representative


Signature

November 11, 2004

Date of Signature

Respectfully submitted,



Kourosh Salehi

Registration No.: 43,898

OSTROLENK, FABER, GERB & SOFFEN, LLP

1180 Avenue of the Americas

New York, New York 10036-8403

Telephone: (212) 382-0700

KS:gl

AMENDMENTS TO THE DRAWINGS

Fig. 1 has been amended. The attached sheet of formal drawings replaces the original sheet including Fig. 1.